



In situ synthesis of cobalt–phosphate (Co–Pi) modified g-C₃N₄ photocatalysts with enhanced photocatalytic activities



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ABSTRACT

The novel cobalt–phosphate (Co–Pi) modified graphitic carbon nitride (g-C₃N₄) photocatalysts were synthesized by “in situ” surface photodeposition process to enhance photocatalytic H₂ and O₂ evolution performance. The resulting Co–Pi/g-C₃N₄ composite photocatalysts were characterized by X-ray diffraction (XRD), scanning electron microscopy (SEM), X-ray photoelectron spectroscopy (XPS) and photoluminescence spectroscopy (PL). The photoelectrochemical measurements of the composite materials were also performed under visible light irradiation. In the photodeposition process, the photogenerated holes in the valence band can oxidize Co²⁺ ions into Co³⁺ ions and cause the deposition of Co–Pi catalysts on the g-C₃N₄ surface. The photocatalytic results indicate that the Co–Pi catalysts can promote the separation of photogenerated charge carriers in g-C₃N₄ and enhance H₂ and O₂ evolutions. One of the synthesized samples CP-20 exhibits the highest catalytic activity. The corresponding O₂ and H₂ evolutions of the CP-20 are 6.8 and 9.6 times than the photocatalytic activities of unmodified g-C₃N₄. A possible mechanism on the improvement of visible light performance is proposed; and this can pave the way for the design and synthesis of new photocatalytic materials.

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1. Introduction

The solar energy driven water splitting and pollutants degradation through semiconductor photocatalysis is of great importance as it is a promising technique for renewable energy production and environmental purification [1–6]. Efficient photocatalytic process requires both a highly active semiconductor catalyst and good working stability, especially for water splitting reaction [7–11]. Many visible light photocatalysts have been designed and explored in order to efficiently utilize solar energy [12–18]. In spite of great research efforts in recent decades for visible-light-driven photocatalysts [19–23], the number of semiconductors with high photocatalytic efficiency and stability under visible light illumination is still limited [24]. Therefore, developing new and more efficient visible light photocatalysts has become crucial to meet the requirements of future solar energy technologies.

As the most stable phase of carbon nitride compounds under ambient conditions, polymeric graphitic carbon nitride (g-C₃N₄)

has received much attention as a promising “metal-free” photocatalyst working under visible light [25]. g-C₃N₄ has an ideal bandgap (E_g) of approximately 2.7 eV [25,26], which allows for utilizing a significant visible portion of the solar spectrum [27,28]. Its conduction band and valence band positions have sufficient overpotential for H₂ and O₂ evolution [29]. Furthermore, g-C₃N₄ is composed of inexpensive “earth abundant” elements, and can be synthesized by facile synthetic methods [30,31]. However, for use as an efficient photocatalyst for water splitting, g-C₃N₄ suffers from low separation efficiency of photogenerated electron–hole pairs [32]. Many strategies have been developed to overcome these challenges, which include the synthesis of novel nanostructures [33,34], tuning compositions [35–38], construction of heterojunctions [39–41] and sensitizing the materials by organic dyes [42]. Recently, Zhang et al. [29] reported the Co₃O₄/g-C₃N₄ hybrid photocatalysts with enhanced O₂ evolution activity, indicating that Co-based species can be used to improve the photocatalytic activity in the C₃N₄ based materials.

Recently, earth abundant cobalt phosphate (Co–Pi) has been demonstrated to work effectively as oxygen-evolving electrocatalyst [43–45]. This material has attractive characteristics such as the low cost and self-repairing behavior [46,47]. The Co–Pi species has been effectively integrated with semiconductors such as ZnO [44], WO₃ [48], α -Fe₂O₃ [49], Si [50] and BiVO₄ [51,52], in order to

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enhance the performance of photocatalytic efficiency. So far, most of the reports have focused on the improved photocurrent in photoelectrochemical water oxidation for O_2 evolution. Very recently, Wang et al. [53] prepared Co-Pi/BiVO₄ photocatalysts via photodeposition process, and found that the O_2 evolution can be enhanced to 6.8 times on the composite catalysts. Xu et al. [54] synthesized Co-Pi/ZnO hybrid photocatalysts, the enhanced activity for O_2 evolution was observed in water oxidation, and the O_2 evolution was more than 4 times of that obtained from pure ZnO. Therefore, it is desirable to deposit Co-Pi on alternative photocatalysts and to further understand the synergistic effect of Co-Pi and other materials.

In this work, for the first time, the novel Co-Pi/g-C₃N₄ composite photocatalysts were synthesized via a facile “in situ” photodeposition method. The photocatalytic O_2 and H_2 evolution via water splitting were investigated under visible light irradiation to evaluate the catalytic performance of composite samples. The Co-Pi modified g-C₃N₄ exhibited significantly enhanced photocatalytic activity, and the g-C₃N₄ with deposition time of 20 min (CP-20) showed the highest performance. The corresponding O_2 and H_2 evolution activities were 6.8 and 9.6 times higher than that of pure g-C₃N₄. The effects of increased light absorption, efficient charge transfer and separation on the photocatalytic performance were discussed in detail. A possible photocatalytic mechanism was proposed based on the experimental results. This study provides a facile way to synthesize photocatalysts made of earth abundant elements for potential high-efficiency photocatalytic applications.

2. Experimental

2.1. Synthesis of the photocatalysts

All chemicals were reagent grade and used without further purification. The metal-free g-C₃N₄ powders were synthesized by heating 2.0 g of cyanamide in an alumina combustion boat under nitrogen gas flow (10 ml/min) to 550 °C at a heating rate of 10 °C min⁻¹ followed by 4 h at that temperature prior to cooling. The product was collected and ground into a powder.

“In situ” synthesis of Co-Pi/g-C₃N₄ composite photocatalysts was described as follows: 0.4 g g-C₃N₄ was immersed in a glass beaker with 100 ml aqueous buffer solution (pH=7) containing 0.1 M potassium phosphate and 0.5 mM cobalt nitrate hexahydrate (Co(NO₃)₂·6H₂O). Photodepositions were performed using a PLS-SXE 300UV Xe arc lamp as UV light source. The mixed g-C₃N₄ and buffer solution were mechanically stirred for several minutes under UV light irradiation. After photodepositions, samples were rinsed thoroughly with distilled water and dried in vacuum environment. The UV irradiation time of Co-Pi/g-C₃N₄ composite samples were 5, 10, 20, 30, 60 min; the resulting samples were denoted as CP-5, CP-10, CP-20, CP-30 and CP-60, respectively.

2.2. Characterization

The crystal structure of the samples was investigated using X-ray diffraction (XRD; Bruker D8 Advance X-ray diffractometer) with Cu K α radiation at a scan rate of 0.1° 2 θ s⁻¹. The accelerating voltage and the applied current were 40 kV and 40 mA, respectively. The morphology of the samples was examined by field emission scanning electron microscopy (SEM; FEI Quanta 200F; accelerating voltage = 10 kV). X-ray photoelectron spectroscopy (XPS) measurements were done on a Axis Ultra XPS instrument with an Mg K α source. The photoluminescence (PL) spectra of the photocatalysts were obtained by a Varian Cary Eclipse spectrometer with excitation wavelength of 325 nm.

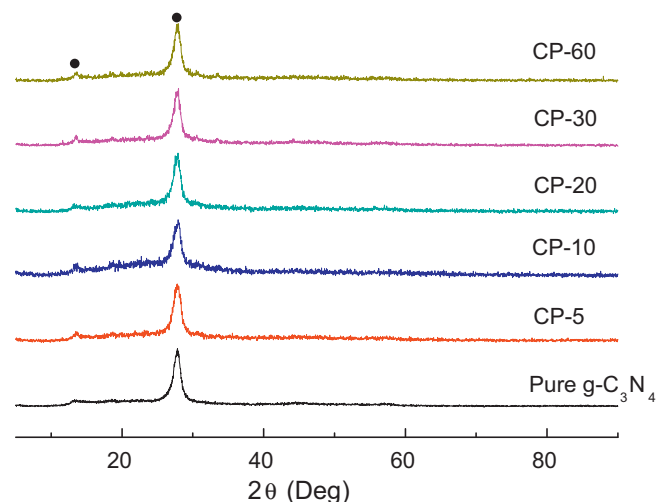


Fig. 1. XRD patterns of pure g-C₃N₄ and the Co-Pi/g-C₃N₄ composite photocatalysts.

2.3. Photocatalytic activity

The photocatalytic H_2 evolution experiments were performed in a 300 ml quartz reactor at ambient temperature. The reactor is connected to a closed circulating system. As light source, a PLS-SXE 300UV Xe arc lamp with a UV-cutoff filter (>400 nm) was used. In a typical photocatalytic experiment, 0.1 g of photocatalyst powder was suspended in 120 ml of aqueous solution containing 25% methanol by volume. The loading of 1.0 wt% Pt co-catalyst was conducted by directly dissolving H₂PtCl₆ into the mentioned suspension. Next, the suspensions were stirred and irradiated (300 W Xe arc lamp) for 30 min at room temperature to reduce the Pt species. Before photocatalytic experiments, the reaction vessel was evacuated for 30 min to remove the dissolved oxygen and to ensure the anaerobic conditions. The products were analyzed by gas chromatography (Shimadzu GC-8A, high purity Argon as a carrier gas) equipped a thermal conductivity detector. The photocatalytic O_2 evolution experiments were similar to the H_2 evolution: 0.1 g of photocatalyst powder was dispersed in 120 ml of 0.05 M silver nitrate (AgNO₃) solution. The suspensions were evacuated for at least 30 min before irradiation to remove dissolved air. Then it was irradiated for 3 h using the 300 W Xe arc lamp with a UV-cutoff filter (>400 nm), and the O_2 evolution were detected by gas chromatography (Shimadzu GC-8A).

2.4. Photoelectrochemical measurements

Photocurrent measurements were performed on an electrochemical analyzer (Solartron SI 1287 Instruments) in a standard three-electrode configuration with a Pt wire as the counter electrode, and Ag/AgCl (in saturated KCl) as a reference electrode. Irradiation proceeded by a Xe arc lamp through a UV-cutoff filter ($\lambda > 420$ nm). Na₂SO₄ (0.01 M) aqueous solution was used as the electrolyte. The working electrodes were prepared as follows: the 0.05 g ground sample was mixed with 1 ml distilled water and 0.1 ml Liquion solution (Ion Power Inc.) was added to make slurry. The slurry was then injected onto a 2 cm × 0.5 cm FTO glass electrode and these electrolytes were dried at 120 °C for 30 min.

3. Results and discussion

3.1. Characterization of Co-Pi/g-C₃N₄ composite samples

The X-ray diffraction patterns of as-prepared Co-Pi/g-C₃N₄ photocatalysts are shown in Fig. 1. The pure polymeric g-C₃N₄

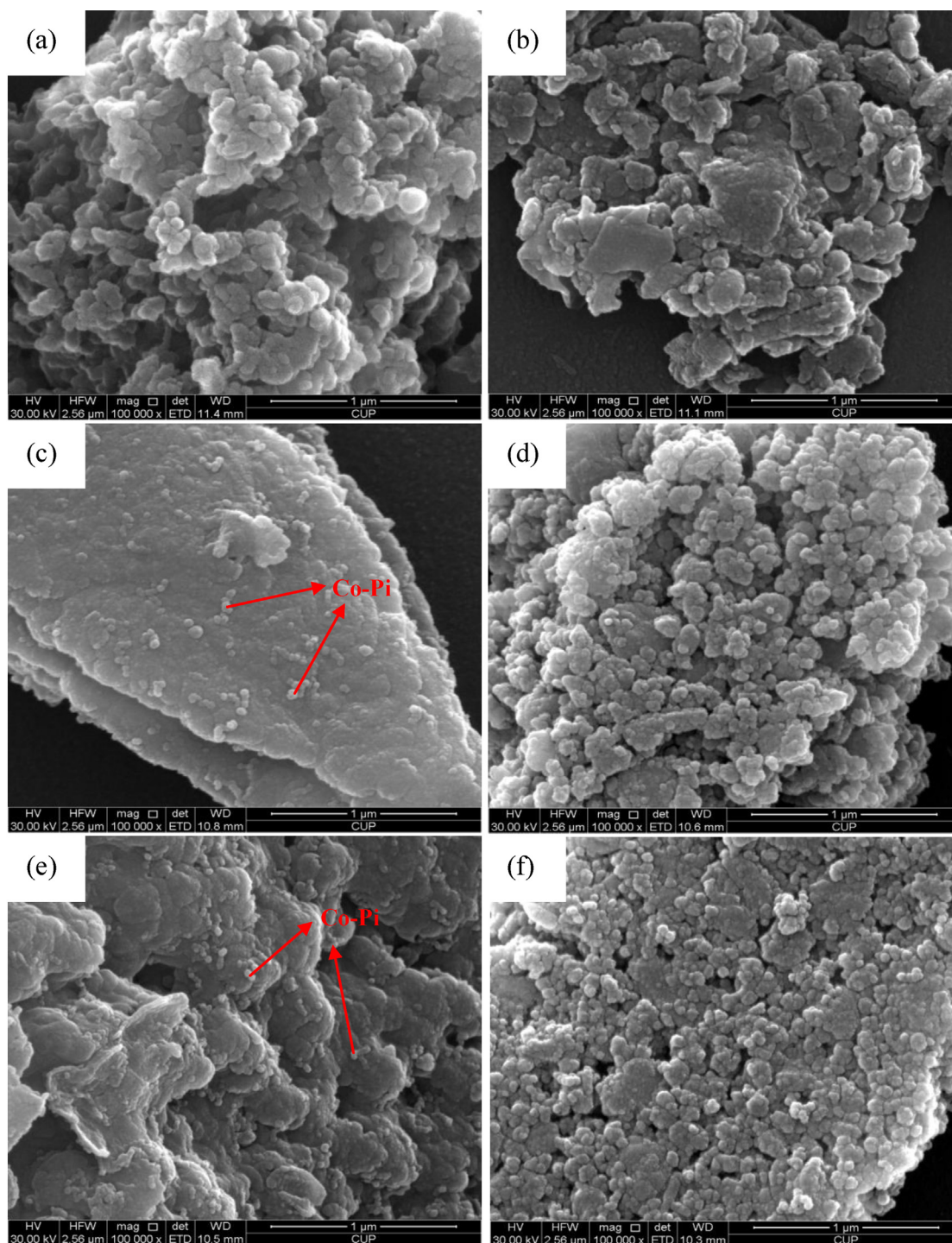


Fig. 2. SEM images of the as-prepared samples: (a) pure g-C₃N₄; (b) CP-5; (c) CP-10; (d) CP-20; (e) CP-30; (f) CP-60.

has two distinct diffraction peaks at 27.5° and 13.2°, which can be indexed for graphitic materials as the (002) and (100) peak in JCPDS 87-1526. These two diffraction peaks are in good agreement with the g-C₃N₄ reported in the literatures [8,40]. However, no diffraction peaks corresponding to Co-Pi species can be observed in Fig. 1. The results indicate that the Co-Pi species photochemically deposited on g-C₃N₄ is amorphous and its presence in sample Co-Pi/g-C₃N₄ cannot be detected by XRD. This is consistent with the findings reported by other researchers about the formation of the amorphous Co-Pi on various semiconductors [44,49,53,54].

The Co-Pi species was deposited on the g-C₃N₄ surface according to literatures [44,49,51,53] in a 0.1 M potassium phosphate solution (pH = 7) with 0.5 mM cobalt nitrate irradiated with UV light. The oxidation potential of Co²⁺ to Co³⁺ is about 0.7 eV vs. NHE; while the VB edge of polymeric g-C₃N₄ is situated at 1.57 eV vs. NHE. As a result the photogenerated holes have enough overpotential to oxidize Co²⁺ to Co³⁺ to yield the Co-Pi species on the surface of g-C₃N₄ [44]. Fig. 2 illustrates the SEM micrographs of pure g-C₃N₄ and Co-Pi/g-C₃N₄ composite samples with different photochemical deposition time. The pure g-C₃N₄ sample appears to have aggregated microstructures comprising a number of 200–300 nm

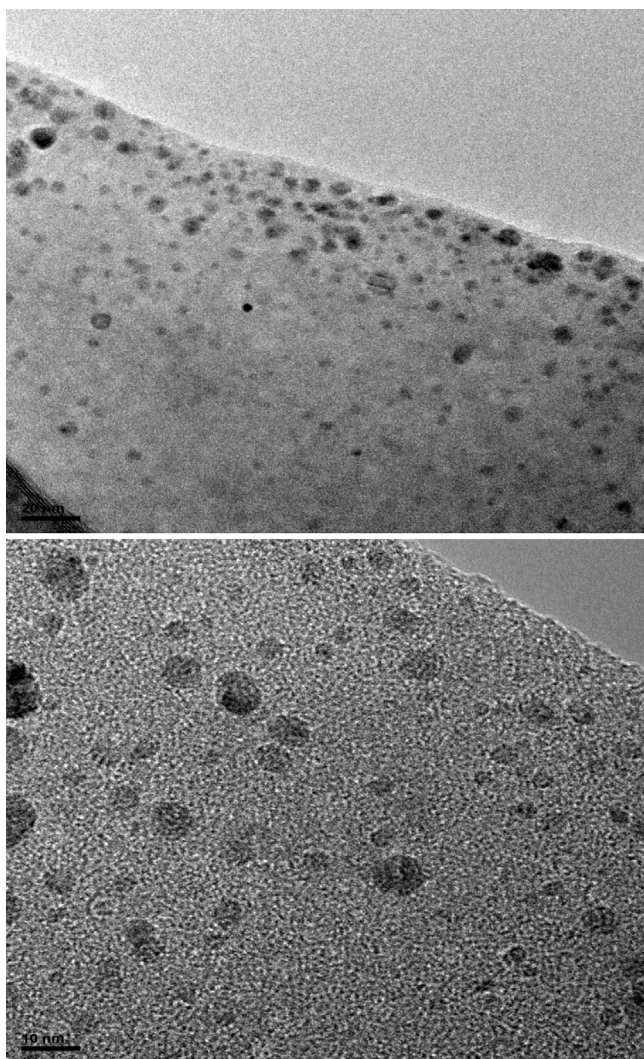


Fig. 3. HRTEM images of Co-Pi/g-C₃N₄ composite photocatalyst (CP-20).

irregular particles. The Co-Pi species are presented as 30–80 nm nanoparticles distributed on the g-C₃N₄ surfaces forming intimate interfaces between Co-Pi and g-C₃N₄ in the hybrid samples. Energy dispersive spectroscopy (EDS) results (Fig. S1) prove that the main compositions of the small nanoparticles are Co-Pi species. And the surface composition of Co-Pi/g-C₃N₄ can be further supported by XPS, as discussed later. More Co-Pi nanoparticles appear on the surfaces of g-C₃N₄ leading to the increased surface coverage with the increase in UV irradiation time. Moreover, the “in situ” photochemical deposition allows the Co-Pi species to be deposited where photogenerated holes are the most readily available. The self-site-selective deposition of Co-Pi species allows the most effective use of Co-Pi in collecting photogenerated holes and promoting electron-hole separation during photocatalytic process.

HRTEM was further used to investigate the microstructures of composite samples. Fig. 3 illustrates HRTEM images with different magnifications for CP-20 sample. After the photochemical deposition of Co-Pi species on g-C₃N₄, the Co-Pi was deposited as nanoparticles on the g-C₃N₄ with high dispersion. The HRTEM results indicate the presence of Co-Pi that forms the intimate interfaces in the composite samples that could favor the charge separation and enhance the photocatalytic efficiency.

The UV–vis diffuse reflectance spectra of as-prepared Co-Pi/g-C₃N₄ composite samples were investigated and shown in Fig. 4. The pure g-C₃N₄ sample shows absorption from the UV through the

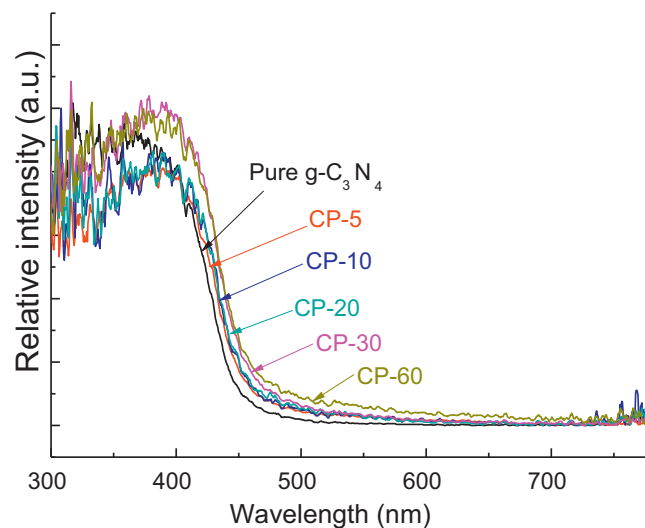


Fig. 4. UV–vis diffuse reflectance spectra of pure g-C₃N₄ and Co-Pi/g-C₃N₄ composite samples.

visible range up to 460 nm. The steep shape of the spectrum indicates that the visible light absorption is ascribed to the band gap transition, corresponding to a band gap of 2.7 eV for g-C₃N₄ [25]. A comparison of the absorption spectra of the pure g-C₃N₄ with the Co-Pi/g-C₃N₄ composite samples shows that the latter exhibit slightly stronger absorption in the visible light region at wavelengths longer than 400 nm, and the red shifts are also observed on the composite samples after “in situ” photodeposition of Co-Pi species. The phenomena may be attributed to the synergistic effect of g-C₃N₄ and Co-Pi co-catalysts in the composite samples. The visible light absorption intensities are also improved with the increase of UV illuminating time for the photodeposition of Co-Pi on the g-C₃N₄ surface and the amounts of Co-Pi deposit (from CP-5 to CP-60). The DRS results also indicate that the photodeposited Co-Pi nanoparticles could enhance the visible light absorption, and hence is expected to increase photocatalytic performance.

The X-ray photoelectron spectrum (XPS) analysis was carried out to gain insight into the chemical composition and binding states on the surface of the Co-Pi/g-C₃N₄ sample. The sample chosen for XPS was CP-20. The XPS spectrum (Fig. S2) shows that the main elements on the surface of the CP-20 are C, N, Co, P and O. The photoelectron peaks appear at binding energies of 288.2 eV (C 1s), 399.1 eV (N 1s), 781.2 (Co 2p), 133.8 (P 2p) and 531.9 eV (O 1s).

Fig. 5 gives the high resolution XPS spectra for CP-20 composite sample in the C 1s (Fig. 5a) and N 1s (Fig. 5b) binding energy regions. The C 1s shows two distinct peaks at 284.78 and 288.12 eV, the first peak can be ascribed to carbon species adsorbed on the surface of g-C₃N₄, the second one represents carbon atoms bonding to three nitrogen atoms in the g-C₃N₄ lattice [8,40]. The N 1s photoelectron signal can be fitted into three peaks located at 398.44, 399.04 and 400.48 eV, respectively. Two peaks at 399.04 and 400.48 eV can be assigned to tertiary nitrogen (N–C₃) and amino functional groups having a hydrogen atom (C–N–H) [40,55]. The peak at 398.44 eV is typically attributed to N atoms with sp² electrons bonded to two carbon atoms (C=N–C). These spectral data agree well with those reported for g-C₃N₄ [8,40,55].

Fig. 6 illustrates the XPS spectra for the Co 2p and P 2p regions after 20 min photodeposition of Co-Pi to the g-C₃N₄ surface. The split peaks of Co 2p are observed at 781.16 and 797.08 eV, corresponding to Co 2p_{3/2} and Co 2p_{1/2} orbits respectively (Fig. 6a). The 781.16 eV can be assigned to Co²⁺, while the other one can be attributed to Co³⁺. The results agree well with the Co-Pi species reported in the literatures [49,54,56]. The P 2p region shows a

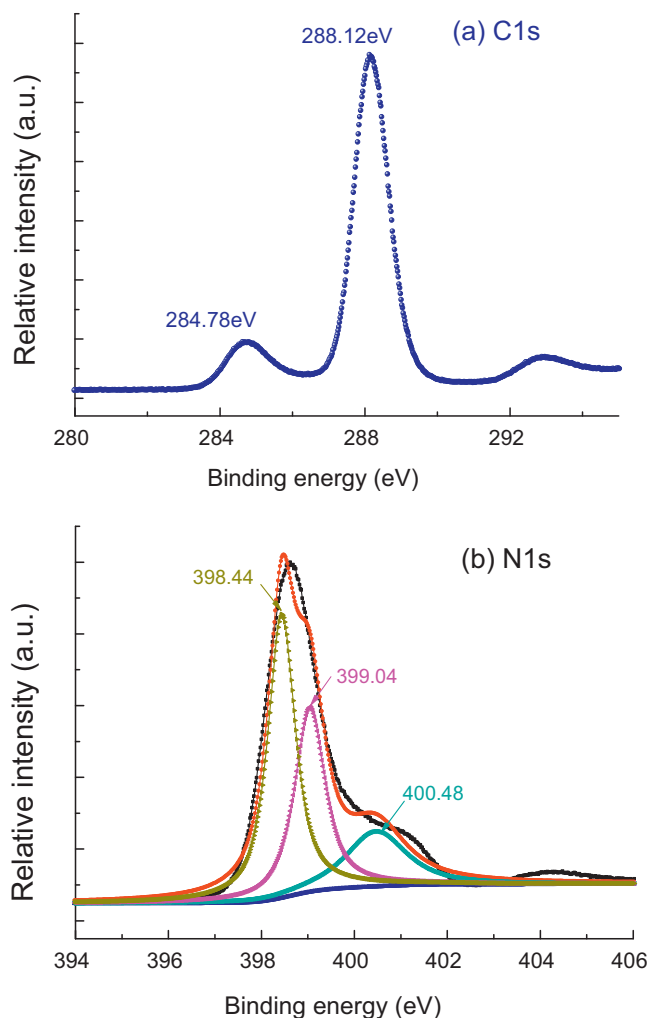


Fig. 5. High-resolution XPS spectra of Co-Pi/g-C₃N₄ composite sample: (a) C1s; (b) N1s.

single peak at 133.7 eV due to phosphate in the Co-Pi co-catalysts [53,54,56]. The existence of Co³⁺ in the sample suggests that Co²⁺ is partially oxidized into Co³⁺ during the photodeposition process. The atomic Co:P ratio in the Co-Pi species is estimated by integrating the Co 2p and P 2p XPS spectra (Table S1), and the results indicate that the atomic ratio of Co:P is 1:0.98. The ratio value is consistent with the number reported in the references [49,53]. Therefore, the XPS results confirmed that the Co-Pi species has been successfully deposited on the g-C₃N₄ photocatalyst in the photodeposition process.

3.2. Photocatalytic performance

The photocatalytic activities of the Co-Pi/g-C₃N₄ composite samples were evaluated by oxygen and hydrogen evolution in aqueous solutions with sacrificial reagents under visible light irradiation (>400 nm). Fig. 7 shows the O₂ evolution curves of Co-Pi/g-C₃N₄ photocatalysts prepared with different photodeposition time, together with the result of pure g-C₃N₄ for comparison using silver nitrate as sacrificial agent. The results demonstrate that the photocatalytic O₂ evolution of pure g-C₃N₄ is very low under visible light irradiation, only 1.28 μmol O₂ is collected after irradiating for 3 h. Wang et al. [54] observed only a trace amount of oxygen generated from pure Co-Pi, indicating that the Co-Pi itself is inactive in oxygen evolution. After photodeposition Co-Pi co-catalyst on g-C₃N₄, the activity of O₂ evolution is enhanced

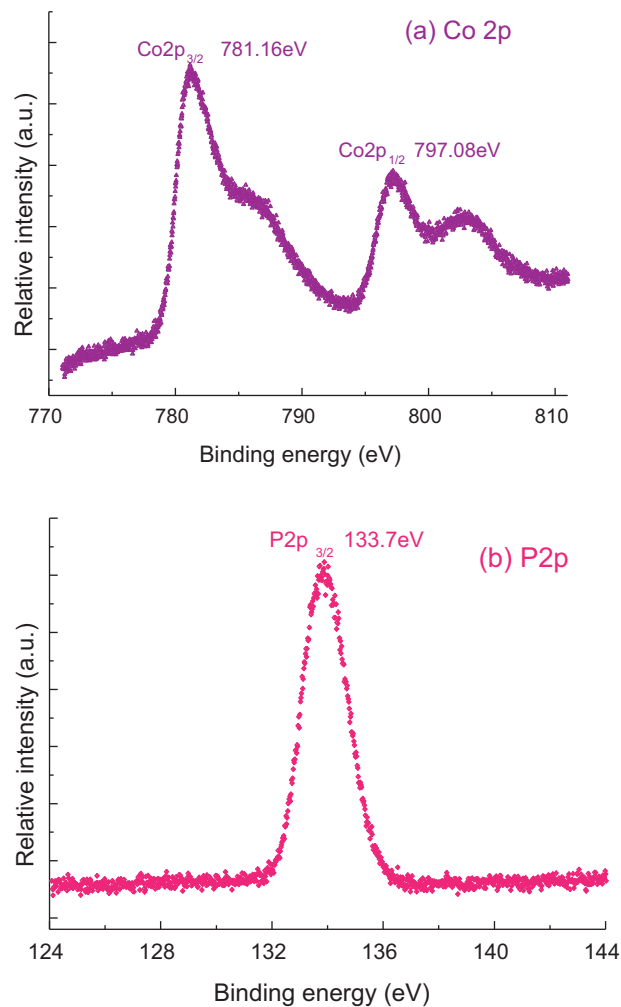


Fig. 6. High-resolution XPS spectra of Co 2p and P 2p of Co-Pi/g-C₃N₄ composite sample.

dramatically. The composite sample CP-20 shows the highest O₂ evolving rate. The activity is 6.8 times better than that of pure g-C₃N₄. The amount of Co-Pi is important for the O₂ evolution activity of the composite Co-Pi/g-C₃N₄. In this study, the optimal photodeposition time is 20 min and the CP-20 sample shows the highest O₂ evolution activity.

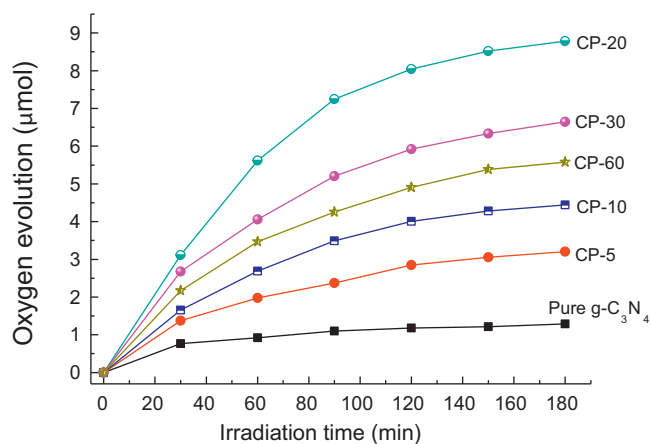


Fig. 7. Photocatalytic O₂ evolution curves of Co-Pi/g-C₃N₄ composite catalysts from 0.02 M silver nitrate aqueous solution under visible light illumination ($\lambda > 400$ nm).

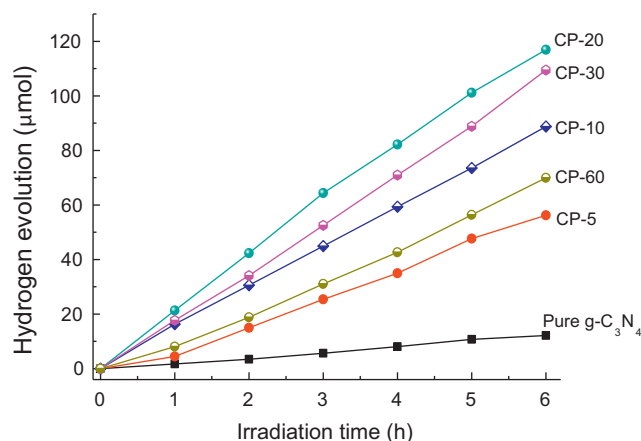


Fig. 8. Photocatalytic H₂ evolution over Co-Pi/g-C₃N₄ composite samples from 25% methanol aqueous solution under visible light illumination ($\lambda > 400$ nm).

The hydrogen evolution over Co-Pi/g-C₃N₄ composite samples was also evaluated in aqueous methanol solution under visible light irradiation, and 1.0 wt% Pt was loaded as a co-catalyst for H₂ evolution. Fig. 8 shows the H₂ production curves for Co-Pi/g-C₃N₄ composite samples. As shown in Fig. 8, pure g-C₃N₄ sample shows visible light photocatalytic activity with H₂ evolution rate of 2.03 $\mu\text{mol h}^{-1}$. After loading Co-Pi on g-C₃N₄ via photodeposition, H₂ evolution is significantly improved. Similar to O₂ evolution, the H₂ production activity of the composite sample is increased from CP-5 to CP-20. The CP-20 sample shows the highest H₂ evolution rate of 19.48 $\mu\text{mol h}^{-1}$, which is about 9.6 folds higher than that of pure g-C₃N₄. The results indicate that the loaded Co-Pi can promote separation of photogenerated electron-hole pairs in g-C₃N₄ and enhance the photocatalytic H₂ and O₂ evolution.

In addition to the photocatalytic activity, the stability of a photocatalyst is important in practical applications. In order to study the stability of Co-Pi/g-C₃N₄ catalysts, the cycling hydrogen evolution experiment of CP-20 sample was performed. Fig. 9 shows the H₂ evolution curve in cycling photocatalytic runs. No significant decrease of H₂ evolution is observed after 48 h of irradiation. The XRD analysis (Fig. S3) confirms that the crystal structure of Co-Pi/g-C₃N₄ composite sample (CP-20) does not change after the photocatalytic reaction. The results indicate sufficient stability of Co-Pi/g-C₃N₄ photocatalyst for hydrogen production.

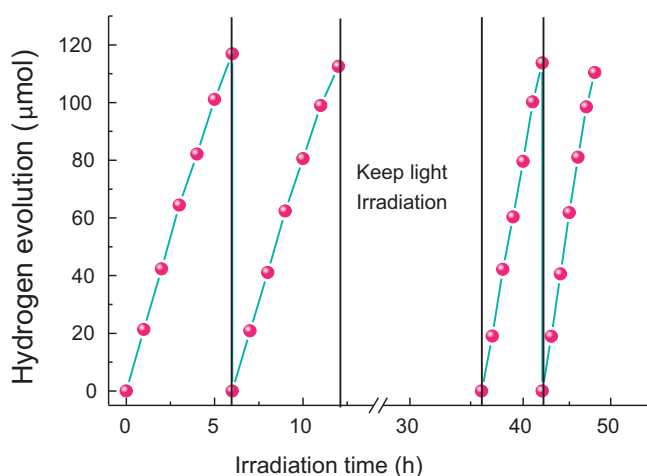


Fig. 9. Cycling runs for the photocatalytic hydrogen evolution in the presence of Co-Pi/g-C₃N₄ (CP-20) composite sample under visible light illumination ($\lambda > 400$ nm).

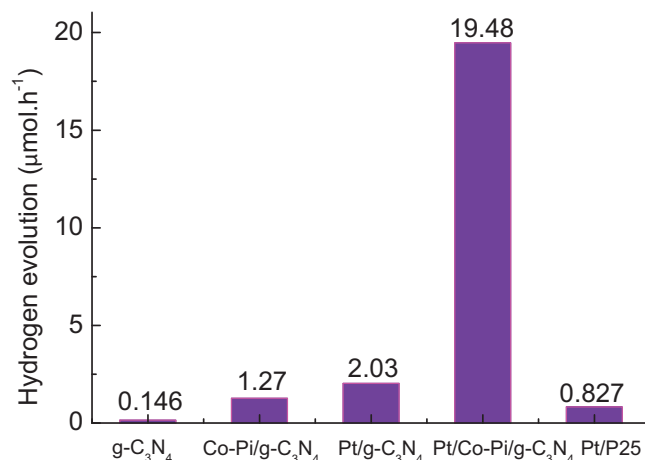


Fig. 10. Comparison of photocatalytic hydrogen evolution on g-C₃N₄ loaded with Co-Pi and Pt, Degussa P25 with 1% Pt from aqueous methanol solution under visible light irradiation.

To further examine the role of Co-Pi in the photocatalytic process, the Pt and Co-Pi were loaded on g-C₃N₄, separately, and their photocatalytic activities were compared. Fig. 10 illustrates the photocatalytic hydrogen evolution of g-C₃N₄ loaded with Co-Pi and Pt, and P25 with 1% Pt loading. The activity of pure g-C₃N₄ without co-catalysts is very low. H₂ evolution is improved upon loading of Co-Pi. The H₂ evolution activity is also increased with the loading 1.0 wt% Pt on g-C₃N₄, indicating that Pt is an efficient co-catalyst for H₂ production. After co-loading the Co-Pi and Pt on g-C₃N₄, the hydrogen evolution is significantly enhanced. The results indicate that the Co-Pi and Pt co-catalyst together can effectively decrease the recombination of electrons and holes in the photocatalytic process. As shown in Fig. 10, the H₂ evolution over Degussa P25 was also carried out as a comparison to the composite photocatalysts [57]. The experimental results reveal that the photocatalytic performance of the Co-Pi/g-C₃N₄ sample is higher than that of P25 photocatalysts under visible light irradiation.

3.3. Photocatalytic mechanism discussion

Based on the results of structure characterization and the visible light photocatalytic activities of the Co-Pi/g-C₃N₄ samples, a possible mechanism is proposed. Fig. 11 shows the "in situ" photodeposition process of Co-Pi on g-C₃N₄. The g-C₃N₄ can be excited under UV light irradiation, and the photogenerated holes have enough overpotential to oxidize Co²⁺ in buffer solution into Co³⁺ ions and form Co-Pi layers with mixed Co²⁺ and Co³⁺ on the g-C₃N₄ surface, whereas the electrons are consumed by the water reduction or react with O₂ in the solution. The Co-Pi nanoparticles are most likely loaded where the holes are generated.

For the photocatalytic process, the efficient charge separation and transfer are crucial for the photocatalytic activity. The Co-Pi species may play a key role in the charge transfer of photogenerated carriers, thus may further contribute to the superior photocatalytic activity of composite samples. As shown in Fig. 12a, for the oxygen evolution reaction, the polymeric semiconductor g-C₃N₄ absorbs photons and excites electron-hole pairs. However, without co-catalysts the photogenerated electrons and holes are likely to recombine, resulting in low photocatalytic activity. The presence of Co-Pi nanoparticles decreases the activation energy of photocatalytic water oxidation. The Co-Pi nanoparticles also serve as the active sites for the oxygen evolution [44,53]. This process also promotes the separation of electron-hole pairs. The electrons reduce the sacrificial reagent Ag⁺ into Ag. This electron-hole separation

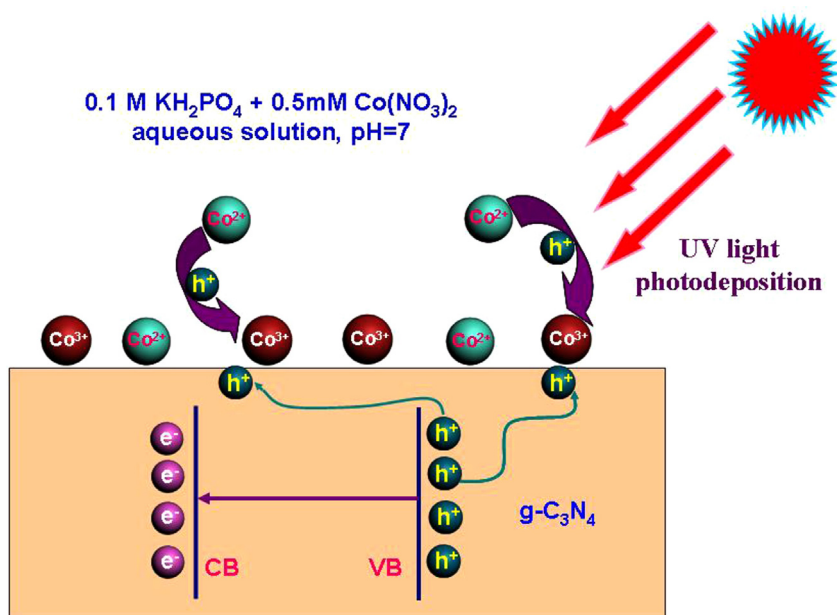


Fig. 11. In situ photochemical deposition of Co-Pi catalyst on the $g\text{-C}_3\text{N}_4$ surface.

leads to enhancement of O_2 evolution in the Co-Pi/ $g\text{-C}_3\text{N}_4$ composite system.

In the photocatalytic hydrogen evolution process as shown in Fig. 12b, both the Co-Pi and Pt are loaded on the $g\text{-C}_3\text{N}_4$ surface.

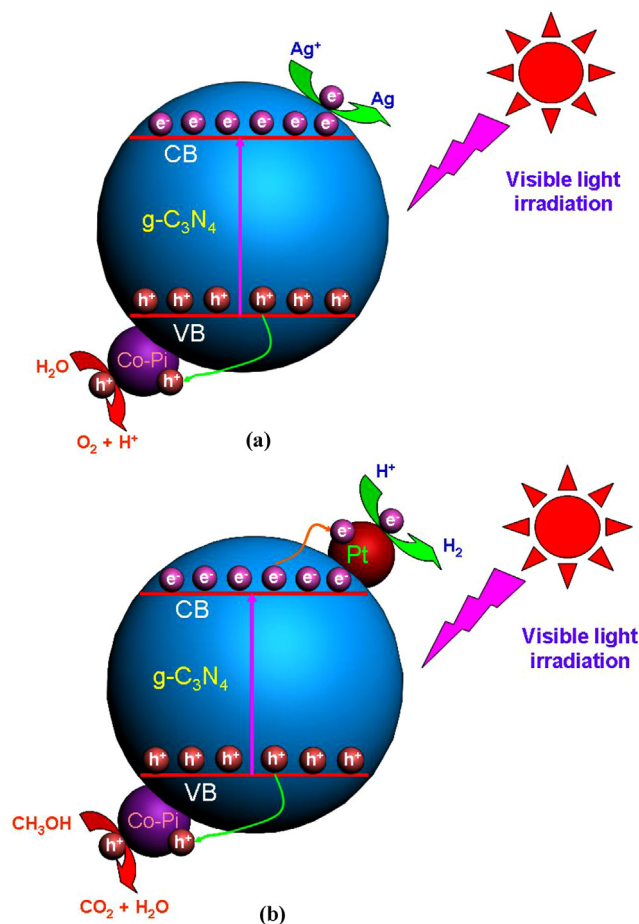


Fig. 12. Proposed photocatalytic mechanisms of Co-Pi/ $g\text{-C}_3\text{N}_4$ composite system under visible light irradiation: (a) oxygen evolution; (b) hydrogen evolution.

The photogenerated electrons could be transferred to Pt and reduce water to form H_2 , whereas the holes could be collected by the Co-Pi co-catalyst. And the holes on the Co-Pi surface would prefer to oxidize sacrificial reagent methanol. Therefore, the recombination process of the electron-hole pairs could be partially resulting in the improvement of H_2 production for the Co-Pi/ $g\text{-C}_3\text{N}_4$ photocatalyst.

In the present experiment, the CP-20 shows the highest H_2 and O_2 evolution rate, which is about 9.6 and 6.8 times higher than that of pure $g\text{-C}_3\text{N}_4$. However, a further increase of photodeposition time can lead to a decrease of water splitting activity. The phenomena can be attributed to loading amount of Co-Pi species. The small amount of Co-Pi may not be sufficient to induce the charge separation. With increasing of UV light irradiation time, more Co-Pi particles are deposited on the surface of $g\text{-C}_3\text{N}_4$. The extra Co-Pi particles can shield the active sites on the photocatalyst surface. As a consequence, a suitable content of Co-Pi is crucial for optimizing the photocatalytic performance of Co-Pi/ $g\text{-C}_3\text{N}_4$ composites.

To further support the proposed photocatalytic mechanism, the photoluminescence emission spectra (PL) and photocurrent curves were performed. Fig. 13 shows the PL spectra for pure $g\text{-C}_3\text{N}_4$ and the composite of Co-Pi/ $g\text{-C}_3\text{N}_4$ samples with an excitation wavelength of 325 nm. The main emission peak centers at about 460 nm for the pure $g\text{-C}_3\text{N}_4$ sample, which can be ascribed to the band gap recombination of electron-hole pairs. The emission intensity of PL spectra for the Co-Pi/ $g\text{-C}_3\text{N}_4$ composites decreases with the increase of photodeposition time. The PL results indicate that the Co-Pi species are effective in the electron-hole pair separation. This could be a reason that the Co-Pi/ $g\text{-C}_3\text{N}_4$ composites show superior photocatalytic activity under visible light.

The photocurrent of as-prepared samples was investigated with chopped light, which generates both dark current and photocurrent during a single sweep. Fig. 14 presents current-time (I - t) curves of pure $g\text{-C}_3\text{N}_4$ and CP-20 electrodes under intermittent visible light irradiation ($\lambda > 420$ nm). Significantly enhanced photocurrent is observed for the Co-Pi photodeposited sample (CP-20) compared to unmodified $g\text{-C}_3\text{N}_4$ sample. This suggests that the Co-Pi can enhance the interfacial charge transfer in the composite Co-Pi/ $g\text{-C}_3\text{N}_4$ sample. The PL spectra and photoelectrochemical (PEC) results support the mechanism discussion above.

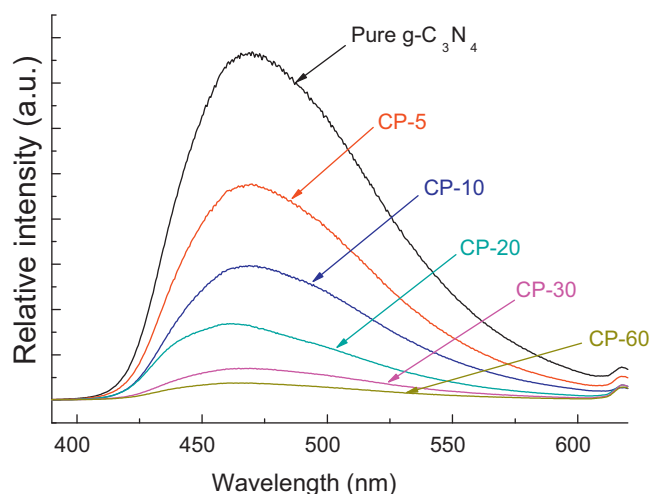


Fig. 13. Comparison of photoluminescence (PL) spectra of pure $g\text{-C}_3\text{N}_4$ and Co-Pi/ $g\text{-C}_3\text{N}_4$ samples.

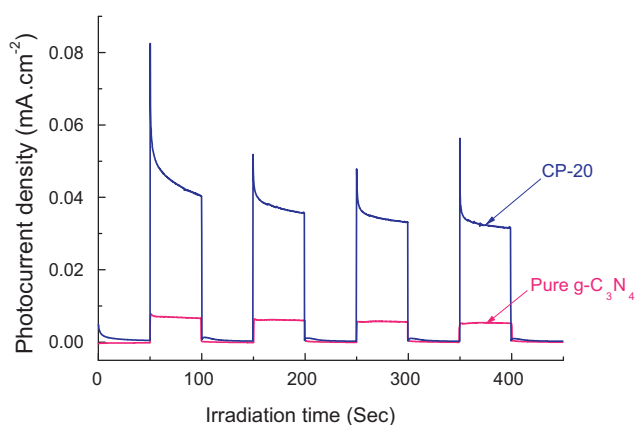


Fig. 14. Transient photocurrent responses ($I-t$) for pure $g\text{-C}_3\text{N}_4$ and CP-20 samples under visible light irradiation at 0.5 V vs. Ag/AgCl.

4. Conclusions

The Co-Pi/ $g\text{-C}_3\text{N}_4$ composite photocatalysts were synthesized via “in situ” photodeposition method. The Co^{2+} is partially oxidized into Co^{3+} to form Co-Pi species during the deposition process. The Co-Pi species are presented as nanoparticles and distributed on the $g\text{-C}_3\text{N}_4$ surface, and the Co-Pi/ $g\text{-C}_3\text{N}_4$ composites exhibit stronger absorption in the visible light region. The Co-Pi/ $g\text{-C}_3\text{N}_4$ composite samples show significantly enhanced H_2 and O_2 evolution activities. The CP-20 sample exhibits the highest catalytic efficiency; corresponding O_2 and H_2 evolution are about 6.8 and 9.6 times than those of pure $g\text{-C}_3\text{N}_4$. The possible photocatalytic mechanism is proposed; the Co-Pi species can promote the separation of photogenerated charge carriers in $g\text{-C}_3\text{N}_4$. The resulting Co-Pi/ $g\text{-C}_3\text{N}_4$ catalyst constituting of earth abundant elements can be an attractive candidate as high performance photocatalysts for water decomposition.

Conflict of interest

The authors declare no competing financial interest.

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Appendix A. Supplementary data

Supplementary data associated with this article can be found, in the online version, at <http://dx.doi.org/10.1016/j.apcatb.2013.05.051>.

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